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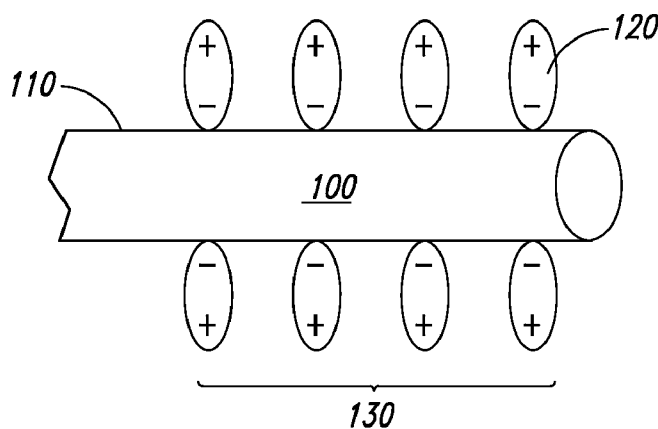
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(54) **Title:** METHOD OF TUNING WORK FUNCTION OF METAL NANOSTRUCTURE-BASED TRANSPARENT CONDUCTOR

**FIG. 3**

(57) **Abstract:** The present disclosure relates to methods for tuning the work function of a metal nanostructure-based conductive film by forming a dipole surface layer on individual metal nanostructures.